TOSHIBA **TA4302F**

TENTATIVE

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA4302F

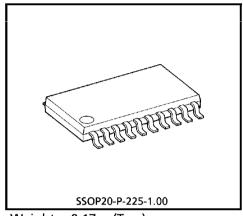
DOWN CONVERTER FOR CATV

DESCRIPTION

The TA4302F is a monolithic IC to down-convert the Lband signal for the CATV tuners. It's integrated circuits that perform the mixer/oscillator function. They have double-balanced mixer, local oscillator, If amplifier, OSC buffer amplifier and prescaler buffer amplifier circuits.

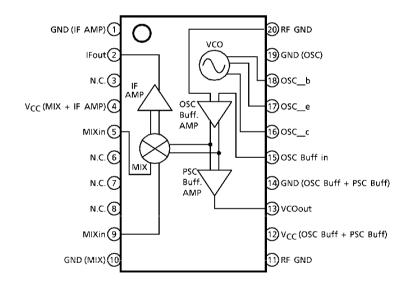
FEATURES

- Single 5 V power supply operation
- Local oscillator output circuit for PLL
- Low Phase Noise local oscillator

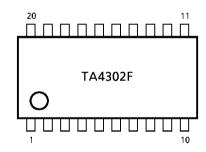


Weight: 0.17 g (Typ.)

PIN CONNECTION / FUNCTION BLOCK DIAGRAM



MARKING



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PIN DESCRIPTION

PIN No.	PIN SYMBOL	PIN VOLTAGE	DESCRIPTION	EQUIVALENT CIRCUIT
1	GND	0	IF amp GND pin	_
2	lFout	2.2	IF output pin	2
3	NC	_	_	_
4	V _{CC} (Amp)	5.0	MIX IF amp power pin	_
5	MIXin-1	1.6	RF input pin	OSC OSC
6	NC	_	_	_
7	NC		_	_
8	NC	_	_	_
9	MIXin-2	1.6	RF GND pin	See the equivalent circuit for pin 5.
10	GND	0	MIX GND pin	_
11	GND	0	GND pin for OSC buffer amp and PSC buffer amp	_
12	V _{CC} (Buff)	5.0	Power pin for OSC buffer amp and PSC buffer amp	_
13	VCOout	1.4	Output pin for local oscillator signal from PSC buffer amp	3
14	GND (Buff)	0	GND pin for OSC buffer amp and PSC buffer amp	_

PIN No.	PIN SYMBOL	PIN VOLTAGE	DESCRIPTION	EQUIVALENT CIRCUIT
15	OSC Buff in	1.4	Input pin for local oscillator signal from OSC buffer amp	15 MIX 220
16	OSC-c	5.0	OSC collector pin, power pin, or local oscillator signal output pin	(B)
17	OSC-e	1.6	OSC emitter pin	17
18	OSC-b	2.4	OSC base pin	
19	GND (OSC)	0	OSC GND pin	_
20	RF GND	1.4	RF GND pin	See the equivalent circuit for pin 5.

MAXIMAM RATINGS ($Ta = 25^{\circ}C$)

CHARACTER	RISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	For Amp	V _{CC} (Amp)	6	V	
Supply Voltage	For OSC	V _{CC} (OSC)	6	\ \ \	
Total Power Dissip	ation	P _D (Note)	1100	mW	
Operating Temper	ature	T _{opr}	- 20∼85	°C	
Storage Temperati	ıre	T _{stg}	- 45∼150	°C	

(Note) $100 \text{ cm}^2 \times 1.6 \text{ t}$ (Cu layer area : 36%) on glass epoxy resins.

RECOMMENDED OPERATING RANGE

CHARACTERISTIC	SYMBOL	VALUE	UNIT
Supply Voltage	V _{CC} (Amp, OSC)	4.5~5.5	V

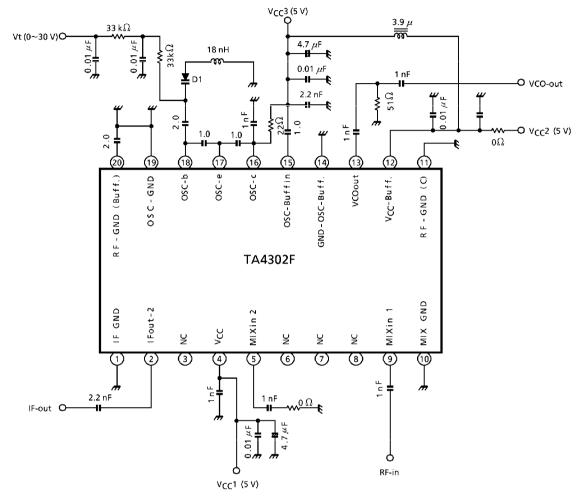
ELECTRIC CHARACTERISTICS (Reference) (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	ICC (Amp)	1	V _{CC} = 5.0 V, No RF input	34	42	50	mΑ
Supply Current	I _{CC} (OSC)	1	V _{CC} = 5.0 V, No RF input	27	32	40	mΑ
Conversion Gain	Gc	1	fin = 955 MHz, fIF = 45 MHz	_	18	23	dB
Noise Figure	NF	1	fin = 955 MHz (SSB), fIF = 45 MHz	_	17.0		dB
Saturation Output	Po (sat)	1	fin = 955 MHz, fIF = 45 MHz	_	(*) + 9		dBmW
Third-order Intercept	IP3	1	fin = 949, 955 MHz fIF = 39, 45 MHz	_	+ 15		dBmW
Phase Noise	P/N	1	fosc = 910 MHz, 10 kHz offset	_	- 85	- 80	dBc/Hz
Oscillator Output Power	VCOout	1	fosc = 910 MHz	_	– 5	_	dBmW

(*) IP3 : Pin = -25 dBmW

(Note) All electrical characteristics measured in Supply Voltage 5.0 V/Amp, 5.0 V/OSC.

TEST CIRCUIT 1

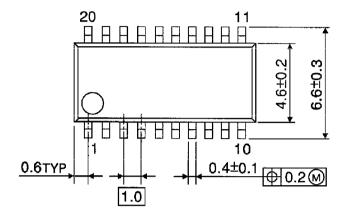


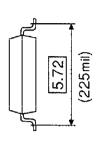
Diode 1SV245

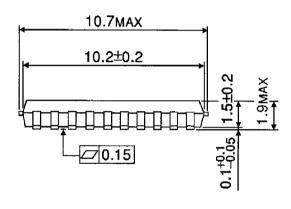
Unit: mm

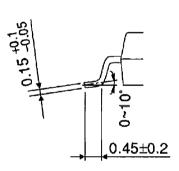
OUTLINE DRAWING

SSOP20-P-225-1.00









Weight: 0.17 g (Typ.)